1/2" - Hiflex

STANDARD

Cable type : *5092*

Reference : *EC4-50-HF*

Cable with standard UV resistant PE jacket, halogen free according to IEC 60754

CHARACTERISTICS

Construction

• Inner conductor	
Material	**copper clad aluminium wire**
Diameter *(mm)*	**3.55**
• Dielectric	
Material	**gas-injected cellular polyethylene**
Diameter *(mm)*	**9.0**
• Outer conductor	
Material	**corrugated copper tube**
Diameter *(mm)*	**12.1**
• Outer sheath	
Material	**black polyethylene**
Thickness *(mm)*	**0.7**
Diameter *(mm)*	**13.6**

Mechanical characteristics

• Minimum bending radius	
a) single bending *(cm)*	**3**
b) 15 repeated bends *(cm)*	**3**
• Maximum pulling strength *(daN)*	**60**
• Recommended temperature range	
- Storage	**-70 to +85 °C**
- Installation	**-40 to +60 °C**
- Operation	**-55 to +85 °C**
• Max. length per hoisting grip *(m)*	**70**
• Maximum hanger spacing *(m)*	**0.5**
• Flat plate crush resistance *(kg/mm)*	**2.1**
• Bending moment *(Nm)*	**2**
• Approximate weight *(kg/km)*	**183**

Electrical characteristics

• Characteristic impedance *(Ω)*	**50.3 ± 0.5**
• Nominal capacity *(pF/m)*	**82**
• Relative propagation velocity *(%)*	**82**
• Inductance *(µH/m)*	**0.204**
• DC-resistance at 20°C	
- inner conductor *(Ω/km)*	**2.76**
- outer conductor *(Ω/km)*	**3.73**
• RF peak voltage *(kV)*	**1.1**
• RF peak power *(kW)*	**23.0**
• Cut-off-frequency *(GHz)*	**13.2**
• Insulation resistance *(M Ω.km)*	**>> 5000**

• Attenuation[1] and power rating

Frequency *(MHz)*	Attenuation at 20°C [2] *(dB/100m)*	Mean power rating [3] *(kW)*
10	1.01	9.45
20	1.43	6.66
30	1.76	5.43
80	2.89	3.30
100	3.24	2.94
150	3.98	2.39
200	4.62	2.06
300	5.69	1.67
400	6.61	1.44
450	7.03	1.36
500	7.43	1.28
600	8.17	1.17
700	8.86	1.08
800	9.51	1.00
894	10.09	0.95
960	10.47	0.91
1000	10.70	0.89
1500	13.30	0.72
1700	14.23	0.67
1800	14.67	0.65
1880	15.02	0.63
2000	15.54	0.61
2170	16.24	0.59
2200	16.36	0.58
2300	16.77	0.57
2400	17.16	0.56
2500	17.55	0.54
2700	18.31	0.52
3000	19.40	0.49
4000	22.77	0.42
6000	28.63	0.33

[1] The attenuation can be approximated by the formula:

$$\alpha(f[MHz]) = A \cdot \sqrt{f[MHz]} + B \cdot f[MHz] \quad (dB/100m)$$

A = 0.317
B = 0.00068

[2] Nominal values
[3] Ambient temperature = 40°C; temperature of inner conductor = 100°C; VSWR = 1.0; no solar loading